Transmissive Optoschmitt Sensor

FEATURES

- Direct TTL interface
- Buffer or inverting logic available
- Three device output options
- Four mounting configurations
- Choice of detector aperture
- 0.125 in.(3.18 mm) slot width

DESCRIPTION

The HOA696X/697X series consists of an infrared emitting diode facing an Optoschmitt detector encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The photodetector consists of a photodiode, amplifier, voltage regulator, Schmitt trigger and various output configurations. The user can choose from available options: (1) detector aperture, (2) mounting tab configuration, (3) detector output configuration, and (4) housing material.

The HOA696X series utilizes an IR transmissive polysulfone housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility.

The HOA697X series employs an opaque polysulfone housing with aperture openings for use in applications in which maximum rejection of ambient light is important, and situations in which maximum position resolution is desired. The HOA696X/697X series employs plastic molded components. For additional component information see SEP8506 and SDP8XX4.

Housing material is polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

Device Polarity:

Buffer - Output is LO when optical path is blocked. Inverter - Output is HI when optical path is blocked.

To specify the complete product characteristics, see PART NUMBER GUIDE.



INFRA-32.TIF

 OUTLINE DIMENSIONS in inches (mm)

 Tolerance
 3 plc decimals
 ±0.010(0.25)

 2 plc decimals
 ±0.020(0.51)

Package T



DIM_066a.cdr Packages N/P/L



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DIM_41b.ds4

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Transmissive Optoschmitt Sensor Totem-Pole Output

ELECTRICAL CHARACTERISTICS (-40°C to +70°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I⊧=20 mA, T₄=25°C
Reverse Leakage Current	IR			10	μA	V _R =3 V, T _A =25°C
DETECTOR						
Operating Supply Voltage	Vcc	4.5		7.0	V	T _A =25°C
Low Level Supply Current	IccL			15	mA	Vcc=5.25 V
High Level Supply Current	Іссн			15	mA	Vcc=5.25 V
Low Level Output Voltage HOA6960/6970 HOA6962/6972	Vol			0.4 0.4	V	V _{CC} =4.75 V, I _{OL} =12.8 mA I _F =0 mA I _F =15 mA
High Level Output Voltage HOA6960/6970 HOA6962/6972	Vон	2.4 2.4			V	V _{CC} =4.75 V, І _{ОН} =800 µА, І _F =15 mA І _F =0 mA
Short Circuit Output Current HOA6960/6970 HOA6962/6972	los	-20 -20		-100 -100	mA	V _{CC} =5.25 V, Output=GND I _F =15 mA I _F =0 mA
Hysteresis (2)	HYST		50		%	
Propagation Delay, Low-High, High-Low	t _{PLH} , t _{PHL}		5		μs	Vcc=5 V, I⊧=0 or 15 mA R∟=8 TTL Loads
Output Rise Time, Output Fall Time	t _r , t _f		70		ns	V _{CC} =5 V, I⊧=0 or 15 mA R∟=8 TTL Loads
COUPLED CHARACTERISTICS IRED Trigger Current	lft			15	mA	Vcc=5 V

Notes 1. It is recommended that a bypass capacitor, 0.1 µF typical, be added between V_{CC} and GND near the device in order to stabilize

 Brecommended inter a system of provide state of the power supply line.
 Hysteresis is defined as the difference between the operating and release threshold intensities, expressed as a percentage of the operate threshold intensity.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted) Operating Temperature Range -40°C to 70°C Storage Temperature Range -40°C to 85°C Soldering Temperature (5 sec) 240°C IR EMITTER 100 mW (1) Power Dissipation 3 V **Reverse Voltage** Continuous Forward Current 50 mA DETECTOR Supply Voltage: Totem-Pole Output 7 V (2) All Others 12 V (2) Duration of Output Short to $V_{\mbox{\scriptsize CC}}$ or Ground 1.0 sec. Notes 1. Derate linearly at 0.78 mW/°C above 25°C.

2. Derate linearly from 25°C to 5.5 V at 70°C.

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Transmissive Optoschmitt Sensor Open-Collector Output

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	l _F =20 mA, T _A =25°C
Reverse Leakage Current	IR			10	μA	V _R =3 V, T _A =25°C
DETECTOR						
Operating Supply Voltage	Vcc	4.5		12	V	T _A =25°C
Low Level Supply Current	lcc∟			15	mA	Vcc=5.25 V
High Level Supply Current	Іссн			15	mA	Vcc=5.25 V
Low Level Output Voltage HOA6961/6971	Vol			0.4	V	V _{CC} =4.75 V, I _{OL} =12.8 mA I⊧=0 mA
HOA6963/6973				0.4 0.4		IF=0 MA IF=15 mA
High Level Output Current HOA6961/6971 HOA6963/6973	Іон			100 100	μA	V _{CC} =4.75 V V _{OH} =30 V I⊧=15 mA I⊧=0 mA
Hysteresis ⁽²⁾	HYST		50		%	
Propagation Delay, Low-High, High-Low	t _{PLH} , t _{PHL}		5		μs	Vcc=5 V, I⊧=0 or 15 mA R∟=390 Ω
Output Rise Time, Output Fall Time	t _r , t _f		70		ns	Vcc=5 V, I⊧=0 or 15 mA R∟=390 Ω
COUPLED CHARACTERISTICS						
IRED Trigger Current	IFT			15	mA	Vcc=5 V

Notes
1. It is recommended that a bypass capacitor, 0.1 µF typical, be added between V_{CC} and GND near the device in order to stabilize power supply line.
2. Hysteresis is defined as the difference between the operating and release threshold intensities, expressed as a percentage of the operate threshold intensity.

ABSOLUTE MAXIMUM RATINGS

ABSOLUTE MAXIMUM RATINGS	
(25°C Free-Air Temperature unless otherwi	ise noted)
Operating Temperature Range	-40°C to 70°C
Storage Temperature Range	-40°C to 70°C
Soldering Temperature (5 sec)	240°C
IR EMITTER	
Power Dissipation	100 mW (1)
Reverse Voltage	3 V
Continuous Forward Current	50 mA
DETECTOR	
Supply Voltage:	
Totem-Pole Output	7 V (2)
All Others	12 V (2)
Duration of Output	
Short to V _{CC} or Ground	1.0 sec.
Applied Output Voltage	35 V
Notes	

1. Derate linearly at 0.78 mW/°C above 25°C.

2. Derate linearly from 25°C to 5.5 V at 70°C.



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Transmissive Optoschmitt Sensor 10 kOhm Pull-Up Output

ELECTRICAL CHARACTERISTICS (-40°C to +70°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	l⊧=20 mA, T _A =25°C
Reverse Leakage Current	IR			10	μA	V _R =3 V, T _A =25°C
DETECTOR						
Operating Supply Voltage	Vcc	4.5		12	V	T _A =25°C
Low Level Supply Current	IccL			15	mA	Vcc=5.25 V
High Level Supply Current	Іссн			15	mA	Vcc=5.25 V
Low Level Output Voltage	Vol				V	Vcc=4.75 V, IoL=12.8 mA
HOA6964/6974				0.4		l _F =0 mA
HOA6965/6975				0.4		I _F =15 mA
High Level Output Voltage	Vон				V	Vcc=4.75 V, Іон=100 µА,
HOA6964/6974		2.4				l _F =15 mA
HOA6965/6975		2.4				I _F =0 mA
Hysteresis (2)	HYST		50		%	
Propagation Delay, Low-High, High-Low	t _{PLH} , t _{PHL}		5		μs	Vcc=5 V, I⊧=0 or 15 mA
						RL=390 Ω
Output Rise Time, Output Fall Time	t _r , t _f		70		ns	Vcc=5 V, IF=0 or 15 mA
						RL=390 Ω
COUPLED CHARACTERISTICS						
IRED Trigger Current	IFT			15	mA	Vcc=5 V

Notes
1. It is recommended that a bypass capacitor, 0.1 µF typical, be added between V_{CC} and GND near the device in order to stabilize power supply line.
2. Hysteresis is defined as the difference between the operating and release threshold intensities, expressed as a percentage of the operate threshold intensity.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise	noted)
Operating Temperature Range	-40°C to 70°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C
IR EMITTER	
Power Dissipation	100 mW (1)
Reverse Voltage	3 V
Continuous Forward Current	50 mA
DETECTOR	
Supply Voltage:	
Totem-Pole Output	7 V (2)
All Others	12 V (2)
Duration of Output	
Short to V _{CC} or Ground	1.0 sec.
Notes	
 Derate linearly at 0.78 mW/°C above 25°C. 	

2. Derate linearly from 25°C to 5.5 V at 70°C.

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Transmissive Optoschmitt Sensor

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Transmissive Optoschmitt Sensor



Fig. 1 IRED Forward Bias Characteristics





Fig. 2 IRED Trigger Current vs Temperature



Aperture Width In Front Of Detector

Aperture length is 0.060 in. (1.52 mm) Aperture Width In Front Of IRED

Aperture length is 0.060 in. (1.52 mm)

L = Single mounting tab, emitter side

P = Single mounting tab, detector side

1 = 0.010 in. (0.25 mm) 5 = 0.050 in. (1.27 mm)

5 = 0.050 In. (1.27 mm)

Mounting Configuration

N = No mounting tabs

T = Two mounting tabs

All Performance Curves Show Typical Values

PART NUMBER GUIDE

HOA69XX-XXX

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<u>с</u> г	Johnsulfond ID	+

6 = Polysulfone, IR transmissive 7 = Polysulfone, opaque

Output Configuration

- 0 = Totem-pole, buffer
- 1 = Open-collector, buffer
- 2 = Totem-pole, inverter
- 3 = Open-collector, inverter
- $4 = 10 \text{ k} \Omega$ pull-up, buffer
- $5 = 10 \text{ k} \Omega$ pull-up, Inverter

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